

ISC Silicon NPN Power Transistor

DESCRIPTION

- · Low Collector Saturation Voltage
 - : V_{CE(sat)}= 0.5V(Max)@ I_C= 3A
- · Collector-Emitter Breakdown Voltage-
 - : V_{(BR)CEO}= 500V (Min)
- · High Switching Speed
- · Minimum Lot-to-Lot variations for robust device performance and reliable operation



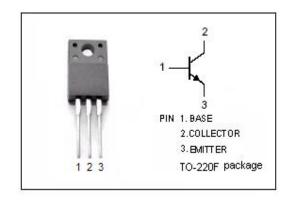
APPLICATIONS

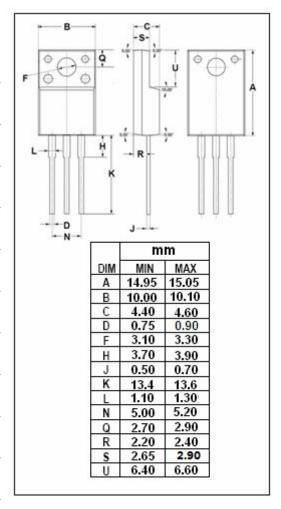
· Designed for switching regulator and general purpose applications.



ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
V _{CBO}	Collector-Base Voltage	500	V
V _{CEO}	Collector-Emitter Voltage	400	V
V _{EBO}	Emitter-Base Voltage	10	V
lc	Collector Current-Continuous	7	Α
Ісм	Collector Current-Pulse	14	Α
I _B	Base Current-Continuous	2	Α
Pc	Collector Power Dissipation @ T _C =25℃ 50		W
TJ	Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range	ange -55~150	







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2SC3832

ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

10-23 C unless otherwise specified								
SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT		
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I _C = 25mA; I _B = 0	400			V		
V _{CE(sat)}	Collector-Emitter Saturation Voltage	I _C = 3A; I _B = 0.6A			0.5	V		
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 3A; I _B = 0.6A			1.3	V		
I _{CBO}	Collector Cutoff Current	V _{CB} = 500V; I _E = 0			100	μ A		
I _{EBO}	Emitter Cutoff Current	V _{EB} = 10V; I _C = 0			100	μ А		
h _{FE}	DC Current Gain	I _C = 3A; V _{CE} = 4V	10		30			
f _T	Current-Gain—Bandwidth Product	I _E = -0.5A; V _{CE} = 12V		10		MHz		
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} = 1.0MHz		50		pF		
Switching times								
t _{on}	Turn-on Time				1.0	μS		
t _{stg}	Storage Time	I _C = 3A; I _{B1} =0.3A; I _{B2} = -0.6A; R _L = 66.7 Ω; V _{CC} = 200V			3.0	μS		
t _f	Fall Time				0.5	μS		

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